

1. 2 Watt Audio Power Amplifier

Features

Improved PSRR at 217 Hz	70dB
Power output at 5.0V, 1% THD+N, 8Ω	1.2W (typ.)
Power output at 3.0V, 1% THD+N, 8Ω	400 mW (typ.)
Ultra low shutdown current	0.1 uA (typ.)
2.2V - 5.5V operation	
Improved circuitry eliminates pop-click n	oise during turn-on and turn-off transitions
Excellent RFI (Radio Frequency Interfere	nce) immunity
No output coupling capacitors, snubber no	etworks or bootstrap capacitors required
Unity-gain stable	
External gain configuration capability	
Available in space-saving package: NLG	A9L

General Description

The BL6213 is a Class-AB audio power amplifier designed for mobile phones and other portable communication devices. It is capable of delivering 1.2 watts of continuous average power to an 8Ω BTL load with less than 1% distortion (THD+N) from a $5V_{DC}$ power supply.

The BL6213 was designed specifically to provide high quality output power with a minimal amount of external components. It does not require output coupling capacitors or bootstrap capacitors. And with ultra low shutdown current, the BL6213 is ideally suited for mobile phone and other low voltage applications where minimal power consumption is a primary requirement.

With special pop-click eliminating circuit, the BL6213 provides perfect pop-click characteristic during turn-on and turn-off transitions.

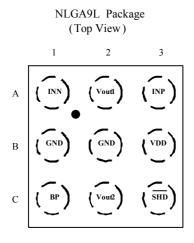
The BL6213 is unity-gain stable and can be configured by external gain-setting resistors.

Applications

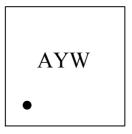
Wireless handsets
Portable electronic devices
PDAs. Handheld computers



Pin Diagrams



NLGA9L Marking (Top View)



A - BL6213

Y - Year Code

W - Week Code

Pin Description

No.	Pin Name	I/O	Description
A1	INN	I	Negative Input
A2	Vout1	O	Negative BTL Output
A3	INP	I	Positive Input
B1/B2	GND	I/O	Ground
В3	VDD	I/O	Power Supply (2.2 – 5.5 V)
C1	BP	I/O	Analog ground for inner OPAs. It's about a half of VDD.
C2	Vout2	О	Positive BTL Output
C3	SHD	I	Shout-down Logical Control, '0' is active.



Typical Application Circuit

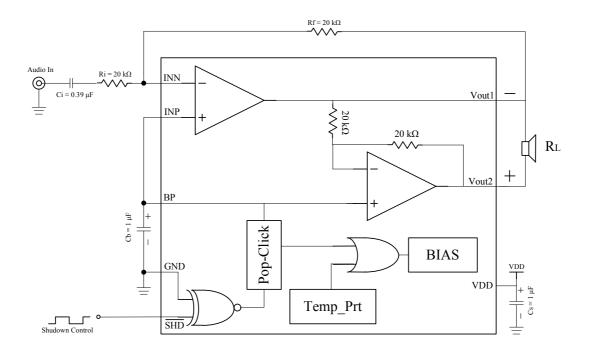


FIGURE 1. BL6213 Typical Application Circuit

External Components Description

Components	Functional Description
Ri	Inverting input resistance which sets the closed-loop gain in conjunction with
	Rf. This resistor also forms a high pass filter with Ci at $fc = 1/(2\pi Ri^*Ci)$.
Ci	Input coupling capacitor which blocks the DC voltage at the amplifiers input
	terminates. Also creates a high-pass filter with Ri at fc = $1/(2\pi Ri*Ci)$.
Rf	Feedback resistance which sets the closed-loop gain in conjunction with Ri.
Cs Supply bypass capacitor which provides power supply filtering.	
Cb	Bypass pin capacitor which provides half-supply filtering. Refer to the section.

Absolute Maximu	m Ratings	Operating Ratings	
Supply Voltage	-0.3V to 6V	Temperature Range	$-40^{\circ}\text{C} \leq T_{A} \leq 85^{\circ}\text{C}$
Input Voltage	-0.3V to VDD+0.3V	Supply Voltage	$2.2V \leq V_{DD} \leq 5.5V$
Junction Temperature	-40°C to $+150$ °C		
Storage Temperature	-65°C to +150°C		



NOTE: Absolute Maximum Ratings indicate limits

performance limits.

beond which damage to the device may occur.

Operating Rating indicate conditions for which the device is functional, but do not guarantee specific

Electrical Characteristics

The following specifications apply for the circuit shown in Figure 1, unless otherwise specified. Limits apply for $T_A = 25 \, ^{\circ} \! \text{C}$.

$$\Box$$
 $V_{DD} = 5V$

C	Parameter	C1:4:	Spec			T I 24
Symbol		Conditions	Min.	Тур.	Max.	Units
т	Quiescent Power Supply	$V_{IN} = 0V$, 8Ω Load		3.6	8	mA
I_{DD}	Current	V _{IN} = 0V, No Load		3.3	7	mA
I_{SD}	Shutdown Current	V _{IN} =0V, V _{SHD} =GND, No Load		0.1	2	uA
V_{SDIH}	Shutdown Voltage Input High		1.3			V
V_{SDIL}	Shutdown Voltage Input Low				0.8	V
V _{OS}	Output Offset Voltage		-50	6	50	mV
THD+N	Total Harmonic Distortion+Noise	Po=0.5Wrms, f=1KHz,		0.13		%
Po	Output Power	THD+N<=1%, f=1KHz, 8Ω Load	0.9	1.2		W
PSRR	Davier Cumbi Paiastian Patia	Input terminated with 10Ω , $V_{DDRIPPLE}$ =0.2 V_{P-P} , f=217Hz	55	68		dB
PSKK	Power Supply Rejection Ratio	Input terminated with 10Ω , $V_{DDRIPPLE}$ =0.2 V_{P-P} , f=1KHz	55	65		dB
T_{WU}	Wake-up time			150		ms

\Box $V_{DD} = 3V$

Cymh al	Parameter	Conditions	Spec			Units
Symbol	rarameter	Conditions	Min.	Тур.	Max.	Units
т	Quiescent Power Supply	$V_{IN} = 0V$, 8Ω Load		3.0	7	mA
I_{DD}	Current	$V_{IN} = 0V$, No Load		2.6	6	mA
I_{SD}	Shutdown Current	V _{IN} =0V, V _{SHD} =GND, No Load		0.1	2	uA
V_{SDIH}	Shutdown Voltage Input High		1.1			V
V_{SDIL}	Shutdown Voltage Input Low				0.6	V



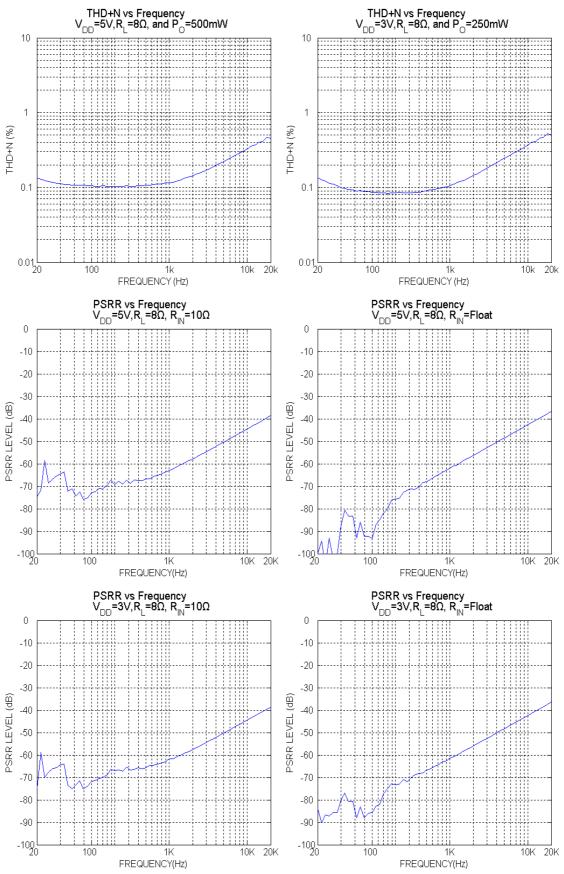
V _{OS}	Output Offset Voltage		-50	6	50	mV
THD+N	Total Harmonic			0.10		%
InD+N	Distortion+Noise	Po=0.25Wrms, f=1KHz,				
D	Output Power	THD+N<=1%, f=1KHz,		400		mW
Po		8Ω Load	40	400		111 VV
	R Power Supply Rejection Ratio	Input terminated with 10Ω ,	55	70		dB
PSRR		$V_{DDRIPPLE}=0.2V_{P-P}, f=217Hz$	33	70		uБ
1 SKK		Input terminated with 10Ω ,	55	65		dB
		$V_{DDRIPPLE}$ =0.2 V_{P-P} , f=1KHz	33	0.5		uБ
T_{WU}	Wake-up time			132		ms

\Box $V_{DD} = 2.6V$

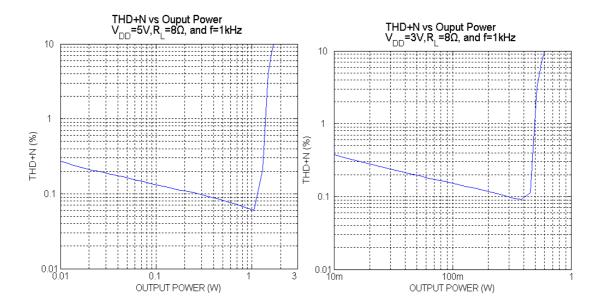
G1	D	G . 122	Spec			T T •4
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
ī	Quiescent Power Supply	$V_{IN} = 0V$, 8Ω Load		2.7		mA
I_{DD}	Current	V _{IN} = 0V, No Load		2.5		mA
I _{SD} Shutdown Current		V _{IN} =0V, V _{SHD} =GND, No Load		0.1		uA
V _{OS}	Output Offset Voltage		-50	4	50	mV
THD+N	Total Harmonic Distortion+Noise	Po=0.15Wrms, f=1KHz,		0.1		%
$P_{\rm O}$	Output Power	THD+N<=1%, $f=1$ KHz, 8Ω Load		300		mW
DCDD		Input terminated with 10Ω, V _{DDRIPPLE} =0.2V _{P-P} , f=217Hz	55	71		dB
PSRR	Power Supply Rejection Ratio	Input terminated with 10Ω, V _{DDRIPPLE} =0.2V _{P-P} , f=1KHz	55	65		dB
T_{WU}	Wake-up time			126		ms



Typical Performance Characteristics



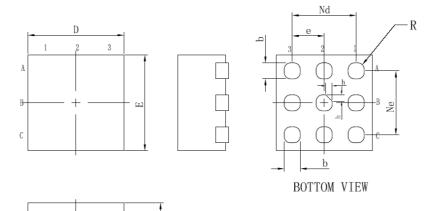






Package Dimensions

NLGA9L PACKAGE



SYMBOL	MILLIMETER				
SIMBOL	MIN	NOM	MAX		
A	0.70	0.75	0.80		
A1	_	0.02	0.05		
b	0. 20	0.25	0.30		
с	0. 20REF				
D	1.40	1.50	1.60		
Nd		1. 00BSC			
e		0. 50BSC			
E	1.40	1.50	1.60		
Ne	1. 00BSC				
h	0.05	0.10	0.15		
R	0. 10REF				